Refine Search

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Terms	Documents
6011277	39

Database:

US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search: L182

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Search History

DATE: Tuesday, August 23, 2005   Printable Copy   Create Case

Set Name	Query	Hit Count	Set Name
side by side			result set
	DB=USPT; PLUR=YES; OP=OR		
L182	6011277	39	L182
L181	6005648	26	L181
L180	5990542	34	L180
L179	5990491	31	L179
L178	5990491	31	L178
L177	5985740	61	L177
L176	5963278	45	L176
L175	5962869	28	L175
L174	5962869L173	0	L174
L173	5940732	21	L173
L172	5940732L171	0	L172
L171	5933205	42	L171
L170	5929464	31	L170
L169	5899547	37	L169

L168	5895933	49	L168
L167	5888858	55	L167
L166	5882960	56	L166
L165	5849611	27	L165
L164	5846857	28	L164
L163	5843225	77	L163
L162	5838508	14	L162
L161	5838508	14	L161
L160	5838508L159	0	L160
L159	5828429	36	L159
L158	5821560	13	L158
L157	5821560L156	0	L157
L156	21560	144	L156
L155	5786796	23	L155
L154	5773327	53	L154
L153	5734179	24	L153
L152	5717224	43	L152
L151	5696003	50	L151
L150	5693541	39	L150
L149	5684365	119	L149
L148	5684317	18	L148
L147	5661311	20	L147
L146	5621244	23	L146
L145	5580815	35	L145
L144	5531182	66	L144
L143	5508207	21	L143
L142	5504019	16	L142
L141	5480811	21	L141
L140	5470763	24	L140
L139	5424230	60	L139
L138	5387530	17	L138
L137	5366926	58	L137
L136	5358907	32	L136
L135	5354697	16	L135
L134	5352291	119	L134
L133	5313075	82	L133
L132	5308998	170	L132
L131	5313075	82	L131
L130	5313075L129	0	L130
L129	5308998	170	L129
L128	5298075	38	L128

L127	5296405	51	L127
L126	5289030	144	L126
L125	5278093	114	L125
L124	5275851	281	L124
L123	5262654	52	L123
L122	5262350	35	L122
L121	5254480	75	L121
L120	5244836	53	L120
L119	5225355	52	L119
L118	5221423	49	L118
L117	5200630	34	L117
L116	5173446	29	L116
L115	5147826	301	L115
L114	5145808	82	L114
L113	5112764	62	L113
L112	5089441	96	L112
L111	5075259	50	L111
L110	5043224	44	L110
L109	4996523	33	L109
L108	4996077	110	L108
L107	4959700	91	L107
L106	4959247	30	L106
L105	4959247	30	L105
L104	4911781	21	L104
L103	4755481	36	L103
L102	4735824	22	L102
L101	4634473	24	L101
L100	4597160	75	L100
L99	4546376	22	L99
L98	L97	48	L98
L97	4544418	48	L97
L96	4534820	32	L96
L95	4481121	34	L95
L94	4472458	27	L94
L93	4409724	83	L93
L92	4379020	56	L92
L91	4331709	34	L91
L90	4309224	65	L90
L89	4300989	47	L89
L88	L87 4300989	65	L88
L87	4277884	31	L87

L86	4271422	38	L86
L85	4231809	62	L85
L84	4226898	419	L84
L83	4174217	49	L83
L82	4132571	17	L82
L81	4068020	60	L81
L80	4059461	132	L80
L79	3783049	43	L79
L78	3389024	19	L78
L77	5818076	51	L77
L76	6278132	11	L76
L75	5728259	17	L75
L74	6175348	10	L74
L73	5824574	43	L73
L72	5821138	79	L72
L71	5818076	51	L71
L70	5811327	30	L70
L69	6,528,820	6	L69
L68	6207969	21	L68
L67	6121683	9	L67
L66	6031249	19	L66
L65	5949107	30	L65
L64	5929527	12	L64
L63	6180439	17	L63
L62	6147667	38	L62
L61	6140165	23	L61
L60	5543636	78	L60
L59	4466073	18	L59
L58	4330363	96	L58
L57	3890632	50	L57
L56	5808321	51	L56
L55	5795795	35	L55
L54	5773847	27	L54
L53	5773846	37	L53
L52	5766977	32	L52
L51	5744824	68	L51
L50	5744822	32	L50
L49	6083801	11	L49
L48	5922125	18	L48
L47	5782665	16	L47
L46	5763899	32	L46

L45	5686328	47	L45
L44	6423586	4	L44

DB=PGPB; PLUR=YES; OP=OR

L43	20020048891	1	L43
L42	20020025659	1	L42

DB=USPT; PLUR=YES; OP=OR

L41	6194254	7	L41
L40	6620711	1	L40
L39	6461943	7	L39
L38	6294441	18	L38
L37	6162704	18	L37
L36	L35	8	L36
L35	4086020	8	L35
L34	6006763	18	L34
L33	5902993	11	L33
L32	5575883	5	L32
L31	5531862	38	L31
L30	6528358	3	L30
L29	6495404	3	L29
L28	6482686	4	L28
L27	6465287	3	L27
L26	6177302	24	L26
L25	5970327	5	L25

DB=JPAB; PLUR=YES; OP=OR

L24	JP05-291220	0	L24
L23	JP 05291220	7408677	L23
L22	JP05291220	0	L22

DB=EPAB; PLUR=YES; OP=OR

L21	L19 and (("first interlayer" or "first insulation") near14 nitride)	0	L21
L20	L19 and ("first interlayer" near10 nitride)	0	L20
L19	FEt or MOSFET	3300	L19

DB=JPAB; PLUR=YES; OP=OR

L18	L17 and (("second interlayer" or "second insulation") near14 resin)	0	L18
L17	L15 and (("first interlayer" or "first insulation") near14 nitride)	1	L17
L16	L15 and ("first interlayer" near10 nitride)	0	L16
L15	FEt or MOSFET	28158	L15

DB=PGPB; PLUR=YES; OP=OR

L14	L13 and (black or opaque or shield)	2	L14
L13	L12 and (("second interlayer" or "second insulation") near14 resin)	2	L13
L12	L11 and (("fourth interlayer" or "fourth insulation"))	2	L12
L11	L10 and (("third interlayer" or "third insulation") near14 resin)	9	L11

L10	L9 and (("second interlayer" or "second insulation") near14 resin)	21	L10
L9	L7 and (("first interlayer" or "first insulation") near14 nitride)	109	L9
L8	L7 and ("first interlayer" near10 nitride)	65	L8
L7	FEt or MOSFET	23677	L7

DB=USPT; PLUR=YES; OP=OR

L6	L5 and "pixel electrode"	19	L6
L5	L4 and (black or opaque or shield)	19	L5
L4	L3 and (("second interlayer" or "second insulation") near14 resin)	31	L4
L3	L1 and (("first interlayer" or "first insulation") near14 nitride)	146	L3
L2	L1 and ("first interlayer" near10 nitride)	84	L2
L1	FEt or MOSFET	71489	L1

END OF SEARCH HISTORY